Impedance Minimization by Nonlinear Tapering

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Outline

- Motivation
- Review of theoretical results
- Optimal boundary
- EM solvers used
- Results for impedance reduction
- Conclusion



Z-optimization by non-linear tapering is not that new

Apart from acoustics, used for gyrotron tapers, mode converters, antennae design, etc.

Examples of Accelerator Tapers & Motivation and Scope of This Work

NSLS MGU Taper for X13, X25, X29 & X9



 $h_{\rm max}/h_{\rm min}$ ~ 9 (gap open) or 27 (gap closed)

NSLS-II transition to SC RF cavity



 $h_{\rm max}/h_{\rm min}$ ~10

Focus on large X-sectional variations and gradual tapering; study transverse, broadband geometric impedance @ low frequency inductive regime Important for LS, i.e. at NSLS-II ~3/4 of Z_{\perp} come from ID chambers (RW and tapers)

Goal to reduce Z to avoid instabilities (TMCI) in rings, or ϵ degradation in linacs ...

Inductive Impedance Regime



In inductive regime (low f) Re[Z]~0, Im[Z]~const vs. frequency. We concentrate on this regime and attempt to minimize Z by optimizing the taper profile.

Theory Review

Axially symmetric taper

$$Z_{\perp}(k) \cong -\frac{iZ_0}{2\pi} \int_{-\infty}^{\infty} dz \frac{r'(z)^2}{r(z)^2}$$

K. Yokoya, 1990

Flat rectangular taper 2*w* × 2*h*, *w*>>*h*

$$Z_{y}^{rect}\left(k\right) = -\frac{iZ_{0}w}{4}\int_{-\infty}^{\infty}dz\frac{h'(z)^{2}}{h(z)^{3}}$$

G. Stupakov, 1996, 2007

Elliptical x-section taper 2w × 2h, w>>h

$$Z_x^{ell}\left(k\right) = -\frac{iZ_0}{4\pi} \int_{-\infty}^{\infty} dz \frac{h'(z)^2}{h(z)^2}$$

$$Z_{y}^{ell}\left(k\right) = -\frac{iZ_{0}\pi w}{16}\int_{-\infty}^{\infty}dz\frac{h'(z)}{h(z)}$$

Z_x: *h*<<*L*, *k*<~1/*h*_{min} Z_y: *w*<<*L*, *k*<~2/*w*_{min}

B. Podobedov & S. Krinsky, 2007

These are inductive regime impedances. Tapers are gradual to be effective.

Functionals lend themselves to simple boundary optimization.

Optimizing Boundaries



At h_{max}/h_{min} =20 predict factor of 2 reduction for Z₁ or Z_x, factor of ~3 for Z_v

Can We Trust the Theory that Ignores Corners?

- Optimizations assume smooth boundaries, i.e. ignore "corners"
- Taper with corners can be thought of as a limit of a sequence of smooth structures =>
- Z_{\perp} was found for cornered taper as limit a->0 B. Podobedov & S. Krinsky, 2006
- Corrections due to corners were found on the order of

 $\Delta Z_{\perp}/Z_{\perp} \sim r_{av}/L$, $\Delta Z_{x}/Z_{x} \sim h_{av}/L$, $\Delta Z_{v}/Z_{v} \sim w_{av}/L$ (small for gradual tapers)

For gradual tapers corners add <u>small</u> corrections to the inductive impedance.



Summary of Numerical Calculations

We attempted to check the accuracy of theoretical predictions for impedance reduction by non-linear tapers in axially-symmetric, elliptical, and rectangular geometry using EM field solvers

- ABCI (axially symmetric)
- ECHO (axially symmetric & 3D)
- GDFIDL (3D)

Wakefield code ECHO (TU Darmstadt / DESY)



Zagorodnov I, Weiland T., *TE/TM Field Solver for Particle Beam Simulations without Numerical Cherenkov Radiation//* Physical Review – STAB,8, **2005**.

Wakefield code ECHO (TU Darmstadt / DESY)

- >zero dispersion in z-direction
 >staircase free (second order convergent)
 >moving mesh without interpolation
- in 2.5D stand alone application

accurate results with coarse mesh



in **3D** only solver, modelling and meshing in CST Microwave Studio
 allows for accurate calculations on conventional single-processor PC
 To be parallelized ...

Impedance Reduction for Axially Symmetric Tapers



 $Z_{\perp}[k\Omega/m]$ and reduction due to exponential taper agree well with theory Impedance reduction extends through inductive regime (*k*~1/*r*_{min}) & beyond

Geometry for Rectangular Taper Calculations



Geometry for Elliptical Taper Calculations



Impedance Reduction for Elliptical X-Section Tapers



 $Z_x[k\Omega/m]$ and reduction due to exponential taper agree well with theory

 $Z_v[k\Omega/m]$ is less than theory; Z_v gets reduced due to optimal taper less than predicted

Impedance Reduction vs. Frequency for Elliptical X-Section



 Z_y reduction extends through inductive regime ($k \sim 1/w_{min}$) & beyond Z_x reduction extends through inductive regime ($k \sim 1/h_{min}$) & beyond

Impedance Reduction for Rectangular X-Section Tapers



 $Z_x[k\Omega/m]$ and reduction due to exponential taper agree well with theory

 $Z_{y}[k\Omega/m]$ is less than theory; Z_{y} gets reduced due to optimal taper less than predicted

Results are very similar to elliptical structure

Conclusion

- For gradual tapers with large cross-sectional changes substantial reduction in geometric impedance is achieved by nonlinear taper.
- Theoretical predictions for impedance reduction are confirmed by EM solvers for axially symmetric structures and for Z_x of flat 3D structures. The vertical impedance gets reduced less than predicted, but the linear taper Z_y is lower as well.
- Optimal tapering for Z_x reduces Z_y as well and vice versa. Impedance reduction holds with frequency through the entire inductive impedance range and beyond.
- For fixed transition length, the *h*(z) tapering we consider is the only "knob" to reduce transverse broadband geometric impedance of tapered structures. Replacing true optimal profile with just a few linear pieces works quite well.

References

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Various Impedance Regimes: vertical kick factor



Vertical kick factor for elliptical transition in pg. 14 ($b_{min}=1 \text{ cm}, b_{max}=4.5 \text{ cm}, 2L=20 \text{ cm}$) For large a/b, $\kappa_y \sim 1/\sigma_z$ (inductive regime) down to $\sigma_z \sim a_{min}$, then, for shorter bunch, $\kappa_y \sim \sigma_z^{-1/2}$ (intermediate regime)

For small a/b, κ_y becomes independent of σ_z at $\sigma_z \sim b_{min}b'$ (optical regime)